

2A, 1000V Glass Passivated Fast Recovery Bridge Rectifiers

FEATURES

- Glass passivated junction
- Ideal for automated placement
- High surge current capability
- UL Recognized file # E-326854
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application

MECHANICAL DATA

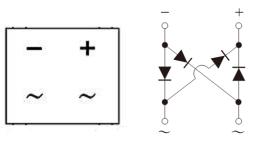
- Case: ABS
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1 whisker test
- Polarity: As marked
- Weight: 0.096 g (approximately)

| KEY PARAMETERS | | |
|--------------------|-------|------|
| PARAMETER | VALUE | UNIT |
| I _F | 2 | А |
| V _{RRM} | 1000 | V |
| I _{FSM} | 50 | А |
| T _{J MAX} | 150 | °C |
| Package | ABS | |
| Configuration | Quad | |









| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | |
|---|---------------------------------|---------------------|-------------|------------------|
| PARAMETER | | SYMBOL | RABS20M | UNIT |
| Marking code on the device | | | RA20M | |
| Repetitive peak reverse voltage | | V _{RRM} | 1000 | V |
| Reverse voltage, total rms value | | V _{R(RMS)} | 700 | V |
| Forward current | | I _F | 2 | А |
| Surge peak forward current, single half | 8.3 ms at $T_A = 25^{\circ}C$ | | 50 | А |
| sine-wave superimposed on rated load per diode | 1.0 ms at T _A = 25°C | I _{FSM} | 120 | А |
| I ² t value (of a surge on-state current) at 8.3ms | | l ² t | 10 | A ² s |
| Junction temperature | | TJ | -55 to +150 | °C |
| Storage temperature | | T _{STG} | -55 to +150 | °C |



| THERMAL PERFORMANCE | | | |
|--|------------------|-----|------|
| PARAMETER | SYMBOL | ТҮР | UNIT |
| Junction-to-lead thermal resistance | $R_{\Theta JL}$ | 39 | °C/W |
| Junction-to-ambient thermal resistance | R _{eja} | 82 | °C/W |
| Junction-to-case thermal resistance | R _{ejc} | 24 | °C/W |

Thermal Performance Note: Units mounted on PCB (5mm x 5mm Cu pad test board)

| ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted) | | | | | |
|--|---|------------------|------|------|------|
| PARAMETER | CONDITIONS | SYMBOL | ТҮР | MAX | UNIT |
| Forward voltage per diode ⁽¹⁾ | $I_F = 1.0A, T_J = 25^{\circ}C$ | | 1.06 | - | V |
| | $I_F = 2.0A, T_J = 25^{\circ}C$ | | 1.16 | 1.30 | V |
| | $I_F = 1.0A, T_J = 125^{\circ}C$ | V _F | 0.89 | - | V |
| | $I_F = 2.0A, T_J = 125^{\circ}C$ | | 1.00 | 1.16 | V |
| Reverse current @ rated V_R per diode $^{(2)}$ | $T_J = 25^{\circ}C$ | - I _R | - | 5 | μA |
| | T _J = 125°C | | - | 90 | μA |
| Junction Capacitance per diode | 1 MHz, V _R =4.0V | Cj | 15 | - | pF |
| Maximum reverse recovery time per diode | IF=0.5A , IR=1.0A I _{RR} =0.25A | t _{rr} | - | 300 | ns |

Notes:

(1) Pulse test with PW=0.3 ms

(2) Pulse test with PW=30 ms

| ORDERING INFORMATION | | |
|----------------------|---------|------------------|
| ORDERING CODE | PACKAGE | PACKING |
| RABS20M M3G | ABS | 1,000 / 7" reel |
| RABS20M M2G | ABS | 5,000 / 13" reel |



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

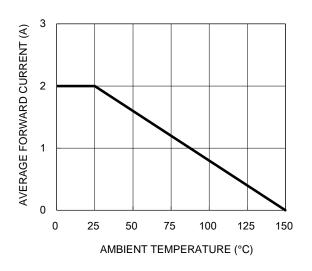
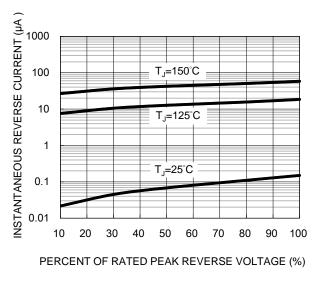
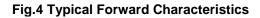


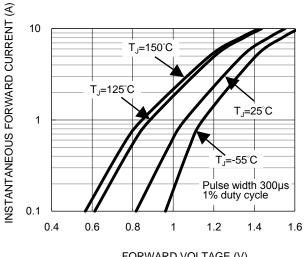
Fig.3 Typical Reverse Characteristics



100 CAPACITANCE (pF) 10 f=1.0MHz Vsig=50mVp-p 1 1 10 100 **REVERSE VOLTAGE (V)**

Fig.2 Typical Junction Capacitance



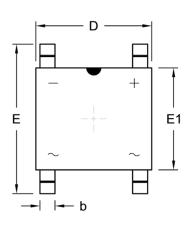


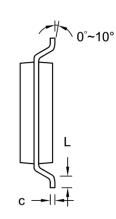
FORWARD VOLTAGE (V)



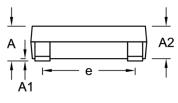
PACKAGE OUTLINE DIMENSIONS

ABS

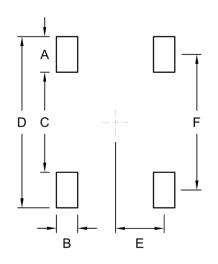




| DIM. | Unit (| | Unit | (inch) | |
|------|--------|------|-------|--------|--|
| DIN. | Min. | Max. | Min. | Max. | |
| А | 1.40 | 1.60 | 0.055 | 0.063 | |
| A1 | 0.05 | 0.15 | 0.002 | 0.006 | |
| A2 | 1.35 | 1.45 | 0.053 | 0.057 | |
| b | 0.60 | 0.70 | 0.024 | 0.028 | |
| с | 0.15 | 0.25 | 0.006 | 0.010 | |
| D | 4.90 | 5.10 | 0.193 | 0.201 | |
| Е | 6.25 | 6.65 | 0.246 | 0.262 | |
| E1 | 4.30 | 4.50 | 0.169 | 0.177 | |
| е | 3.90 | 4.10 | 0.154 | 0.161 | |
| L | 0.30 | 0.70 | 0.012 | 0.028 | |

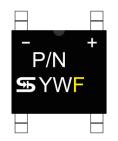


SUGGESTED PAD LAYOUT



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| A | 1.50 | 0.059 |
| В | 0.90 | 0.035 |
| С | 4.22 | 0.166 |
| D | 7.22 | 0.284 |
| E | 2.05 | 0.081 |
| F | 5.72 | 0.225 |

MARKING DIAGRAM



| P/N | = Marking Code |
|-----|----------------|
| YW | = Date Code |
| F | = Factory Code |

= Factory Code



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